



# Advanced CMOS TTL Input – 74ACT38

Quad 2-input NAND buffer (open drain) in bare die form

Rev 1.0  
18/01/21

## Description

74ACT38 provides x4 independent 2-input NAND gates performing the Boolean function  $Y = \overline{A \cdot B}$  or  $Y = \overline{A} + \overline{B}$ . The device is fabricated using an advanced 1.5µm 5V CMOS process combining high speed LSTTL performance with CMOS low power consumption. The provision of open-drain outputs enables implementation of active-low wired-OR or active-high wired-AND functionality. Device inputs directly accept both standard CMOS and LSTTL outputs. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

## Features:

- Inputs directly accept TTL
- Outputs directly interface CMOS, NMOS and TTL
- Open-drain output for wired-OR/wired-AND function
- Outputs Source/Sink 24 mA
- Low Input Current: 1µA
- Functionally compatible with bipolar 74LS38, 74F38
- Lower power alternative to bipolar logic.

## Ordering Information

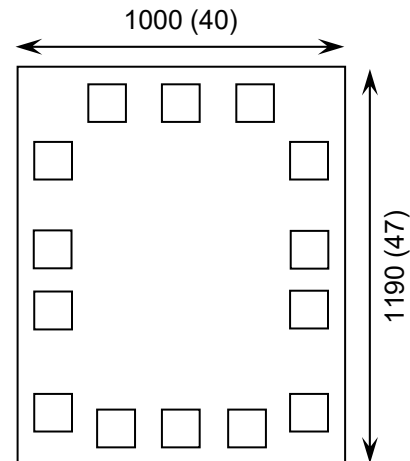
The following part suffixes apply:

- No suffix - MIL-STD-883 /2010B Visual Inspection

For High Reliability versions of this product please see

[54ACT38](#)

## Die Dimensions in µm (mils)



## Supply Formats:

- Default – Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness <=> 350µm(14 Mils) – On request
- Assembled into Ceramic Package – On request

## Mechanical Specification

Die Size (Unsawn)	1000 x 1190 40 x 47	µm mils
Minimum Bond Pad Size	100 x 100 4 x 4	µm mils
Die Thickness	350 (±20) 13.78 (±0.79)	µm mils
Top Metal Composition	Al 1%Si 1.1µm	
Back Metal Composition	N/A – Bare Si	

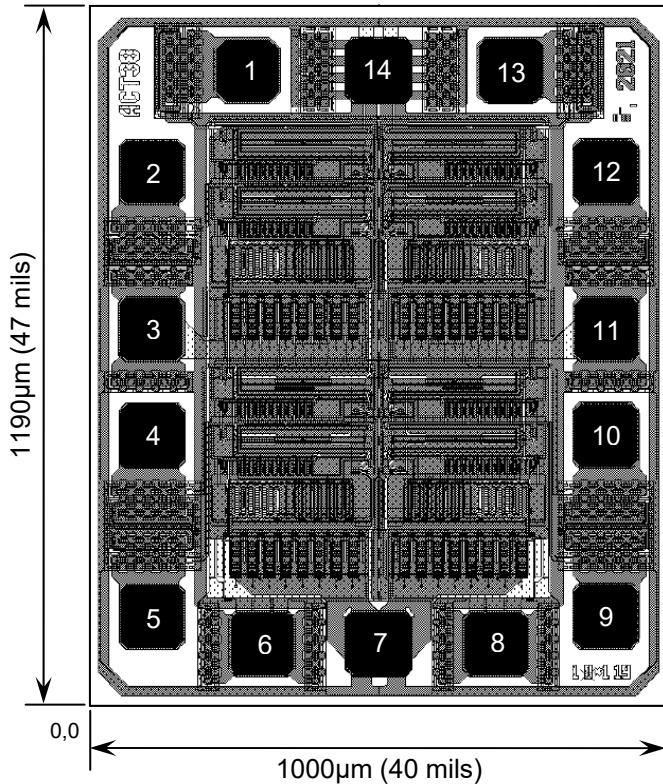




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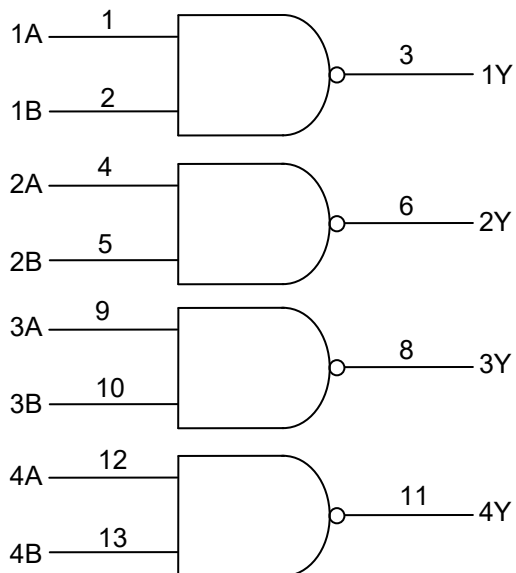
## Pad Layout and Functions



PAD	FUNCTION	COORDINATES (mm)	
		X	Y
1	1A	0.250	0.980
2	1B	0.100	0.820
3	1Y	0.100	0.580
4	2A	0.100	0.420
5	2B	0.100	0.140
6	2Y	0.270	0.100
7	GND	0.450	0.100
8	3Y	0.670	0.100
9	3A	0.790	0.140
10	3B	0.790	0.420
11	4Y	0.790	0.590
12	4A	0.790	0.820
13	4B	0.650	0.980
14	V <sub>CC</sub>	0.450	0.980

CONNECT CHIP BACK TO V<sub>CC</sub> OR FLOAT

## Logic Diagram



## Truth Table

INPUTS		OUTPUT
A	B	Y
L	L	Z
L	H	Z
H	L	Z
H	H	L

H = High level (steady state)  
L = Low level (steady state)  
Z = High Impedance state





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## Absolute Maximum Ratings<sup>1</sup>

PARAMETER	SYMBOL	VALUE	UNIT
DC Supply Voltage (Referenced to GND)	$V_{CC}$	-0.5 to +7.0	V
DC Input or Output Voltage (Referenced to GND)	$V_{IN}, V_{OUT}$	-0.5 to $V_{CC}+0.5$	V
Storage Temperature Range	$T_{STG}$	-65 to 150	°C
Input Current (per Pad)	$I_{IN}$	±20	mA
Output Current (per Pad)	$I_{OUT}$	±50	mA
DC Supply Current, $V_{CC}$ or GND, per pad	$I_{CC}$	±50	mA
Power Dissipation in Still Air <sup>2</sup>	$P_D$	500	mW

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Measured in plastic SSOP package, results in die form are dependent on die attach and assembly method.

## Recommended Operating Conditions<sup>3</sup> (Voltages Referenced to GND)

PARAMETER	SYMBOL	MIN	MAX	UNITS	
DC Supply Voltage	$V_{CC}$	4.5	5.5	V	
DC Input or Output Voltage	$V_{IN}, V_{OUT}$	0	$V_{CC}$	V	
Operating Temperature Range	$T_J$	-55	+125	°C	
Output current - High	$I_{OH}$	-	-24	mA	
Output current - Low	$I_{OL}$	-	24	mA	
Input Rise or Fall rate ( $V_{IN}$ from 0.8V to 2V)	$\Delta t/\Delta V$	$V_{CC} = 4.5V$	0	10	ns/V
		$V_{CC} = 5.5V$	0	8	

3. This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{IN}$  and  $V_{OUT}$  should be constrained to the range  $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$ . Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or  $V_{CC}$ ). Unused outputs must be left open.

## DC Electrical Characteristics (Voltages referenced to GND)

PARAMETER	SYMBOL	$V_{CC}$	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE <sup>4</sup>	
Minimum High-Level Input Voltage	$V_{IH}$	4.5V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$	2	2	2	V
		5.5V		2	2	2	
Maximum Low-Level Input Voltage	$V_{IL}$	4.5V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$	0.8	0.8	0.8	V
		5.5V		0.8	0.8	0.8	
Minimum Low-Level Output Voltage	$V_{OL}$	4.5V	$I_{OUT} = 50\mu A$	0.1	0.1	0.1	V
		5.5V		0.1	0.1	0.1	
		4.5V	$V_{IN} = V_{IL} \text{ or } V_{IH}^5$ $I_{OL} = 24mA$	0.36	0.44	0.44	V
		5.5V		0.36	0.44	0.44	
		4.5V	$V_{IN} = V_{IL} \text{ or } V_{IH}^{5,6}$ $I_{OL} = 50mA$	1.65	1.65	1.65	V
		5.5V		1.65	1.65	1.65	

4.  $-40^\circ C \leq T_J \leq +85^\circ C$  5. All outputs loaded; thresholds on input associated with output under test. 6. Test time 1sec max, measurement made by forcing indicated current and measuring voltage to minimize power dissipation. Test verifies a minimum 75Ω transmission-line drive capability at 85°C





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## DC Electrical Characteristics Continued (Voltages referenced to GND)

PARAMETER	SYMBOL	V <sub>CC</sub>	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE <sup>4</sup>	
Minimum High-Level Output Voltage	V <sub>OH</sub>	4.5V	I <sub>OUT</sub> = -50µA	4.4	4.4	4.4	V
		5.5V		5.4	5.4	5.4	
		4.5V	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> <sup>5</sup>	3.86	3.76	3.76	V
		5.5V	I <sub>OL</sub> = -24mA	4.86	4.76	4.76	
		4.5V	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> <sup>5,6</sup>	-	-	-	V
		5.5V	I <sub>OL</sub> = -50mA	-	-	-	
Maximum Input Leakage Current	I <sub>IN</sub>	5.5V	V <sub>IN</sub> = V <sub>CC</sub> or GND	±0.1	±1.0	±1.0	µA
Maximum 3-State leakage current	I <sub>OZ</sub>	5.5	V <sub>OUT</sub> =V <sub>CC</sub> or GND, V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>	±0.5	±2.5	±2.5	µA
Additional Maximum I <sub>CC</sub> / Input	ΔI <sub>CCT</sub>	5.5V	V <sub>IN</sub> = V <sub>CC</sub> -2.1V	0.6	1.5	1.5	mA
Minimum Dynamic Output Current <sup>7</sup>	I <sub>OLD</sub>	5.5V	V <sub>OLD</sub> = 1.65V Max	-	75	75	mA
	I <sub>OHD</sub>	5.5V	V <sub>OHD</sub> = 3.86V Min	-	-75	-75	
Maximum Quiescent Supply Leakage Current	I <sub>CC</sub>	5.5V	V <sub>IN</sub> = V <sub>CC</sub> or GND I <sub>OUT</sub> = 0µA	4	40	40	µA

7. Maximum test duration 2ms, one output loaded at a time.

## AC Electrical Characteristics<sup>8</sup>

PARAMETER	SYMBOL	V <sub>CC</sub>	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE <sup>4</sup>	
Maximum Propagation Delay, A or B to Y	t <sub>PLH</sub>	5V ±10%	GND = 0V, C <sub>L</sub> = 50pF, R <sub>L</sub> = 500Ω, t <sub>r</sub> = t <sub>f</sub> = ≤ 2.5ns	6	7	7	ns
	t <sub>PHL</sub>			6	7	7	
Maximum Propagation Delay, OFF-state to Low	t <sub>PZL</sub>	5V ±10%	GND = 0V, C <sub>L</sub> = 50pF, R <sub>L</sub> = 500Ω, t <sub>r</sub> = t <sub>f</sub> = ≤ 2.5ns, (Figure1)	5.1	6	6	ns
Maximum Propagation Delay, Low to OFF-state	t <sub>PLZ</sub>			5.0	5.3	5.3	
Maximum Input Capacitance	C <sub>IN</sub>	5V ±10%	V <sub>IN</sub> = V <sub>CC</sub> or GND	8	8	8	pF
Power Dissipation Capacitance <sup>9</sup>	C <sub>PD</sub>	-	T <sub>J</sub> = 25°C, V <sub>CC</sub> = 5.0V	TYPICAL			pF
				40			

8. Not production tested in die form, characterized by chip design.

9. Used to determine the no-load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> V<sub>CC</sub><sup>2</sup>f + I<sub>CC</sub> V<sub>CC</sub>.





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## Switching Waveforms

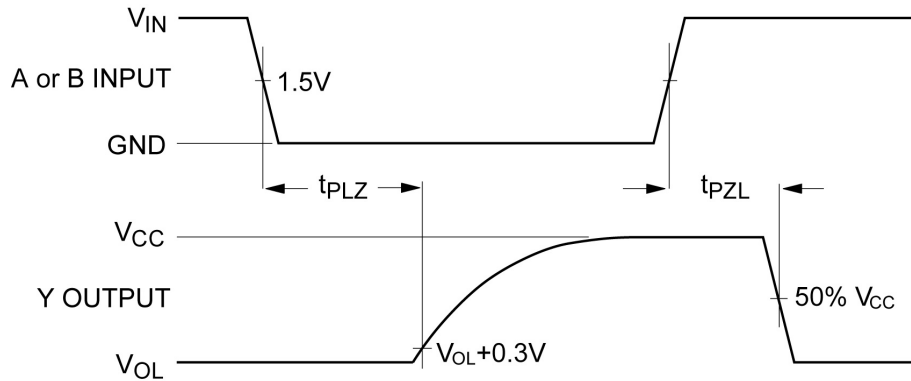
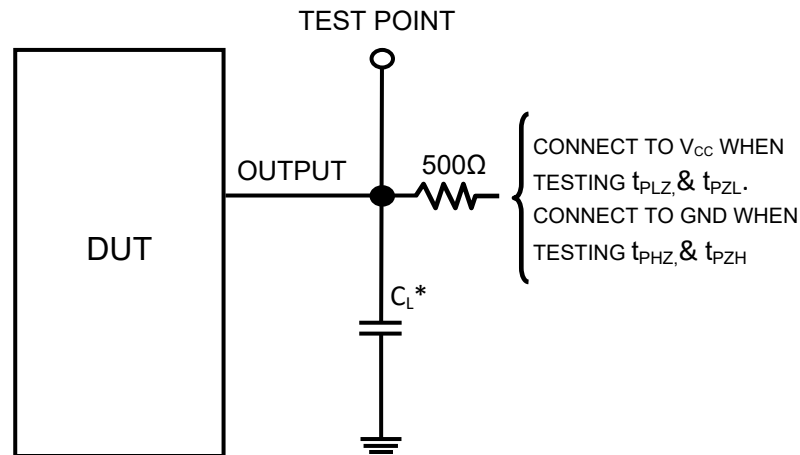


Figure 1 – Propagation Delay, Input A or B to Output Y

## Test Circuit



\* Includes all probe and jig capacitance

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